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Vishay Semiconductors

High Speed Infrared Emitting Diodes, 850 nm, **Surface Emitter Technology**





DESCRIPTION

As part of the SurfLight™ portfolio, the VSMY2850 series are infrared, 850 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

APPLICATIONS

- · Automotive sensors
- · Miniature light barrier
- Photointerrupters
- · Optical switch
- Emitter source for proximity sensors
- IR illumination

FEATURES

Package type: surface-mount

• Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8

AEC-Q101 qualified

Peak wavelength: λ_p = 850 nm

High reliability

· High radiant power

· Very high radiant intensity

• Angle of half intensity: $\varphi = \pm 10^{\circ}$ • Suitable for high pulse current operation

· Terminal configurations: gullwing or reverse

Package matches with detector VEMD2500

Floor life: 4 weeks, MSL 2a, according to J-STD-020

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

· Package form: GW, RGW







gullwing
X01 series
-STD-020

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr)	φ (deg)	λ_{P} (nm)	t _r (ns)	
VSMY2850RGX01	125	± 10	850	10	
VSMY2850GX01	125	± 10	850	10	

Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMY2850RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMY2850GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

Note

· MOQ: minimum order quantity



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	5	V
Forward current		I _F	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA
Surge forward current	t _p = 100 μs	I _{FSM}	1	Α
Power dissipation		P_V	190	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	-40 to +85	°C
Storage temperature range		T _{stg}	-40 to +100	°C
Soldering temperature	According to Fig. 10, J-STD-020	T _{sd}	260	°C
Thermal resistance junction-to-ambient	EIA / JESD51	R _{thJA}	250	K/W

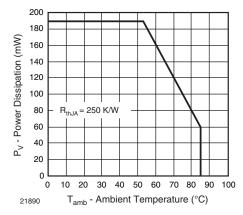


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

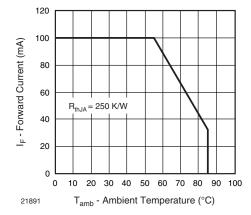


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Familiard violence	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}	-	1.6	1.9	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	V _F	-	2.8	-	V
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}	-	-1.5	-	mV/K
Reverse current		I _R	Not designed for reverse operation µ		μA	
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ	-	50	-	pF
Dadient intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	70	125	210	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	l _e	-	1000	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe	-	55	-	mW
Temperature coefficient of radiant power	$I_F = 100 \text{ mA}$	TKφ _e	-	-0.12	-	%/K
Angle of half intensity		φ	-	± 10	-	deg
Peak wavelength	I _F = 100 mA	λρ	840	850	870	nm
Spectral bandwidth	I _F = 30 mA	Δλ	-	30	-	nm
Temperature coefficient of λ _p	I _F = 30 mA	TKλ _p	-	0.25	-	nm/K
Rise time	I _F = 100 mA, 10 % to 90 %	t _r	-	10	-	ns
Fall time	I _F = 100 mA, 10 % to 90 %	t _f	-	10	-	ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

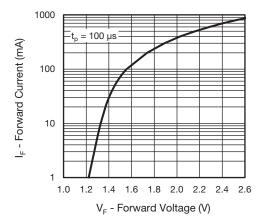


Fig. 3 - Forward Current vs. Forward Voltage

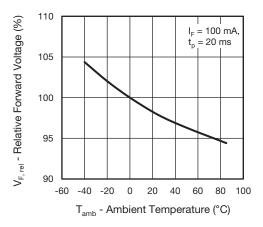


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

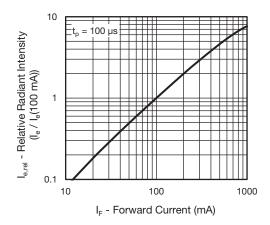


Fig. 5 - Relative Radiant Intensity vs. Forward Current

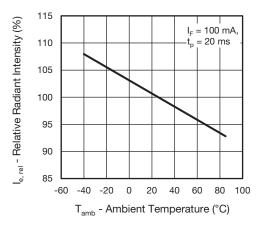


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

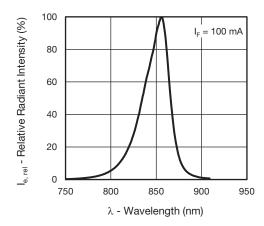


Fig. 7 - Relative Radiant Intensity vs. Wavelength

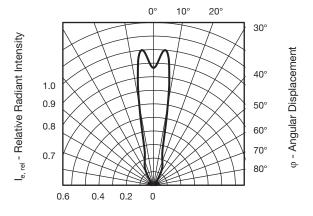


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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VSMY2850RGX01, VSMY2850GX01

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SOLDER PROFILE

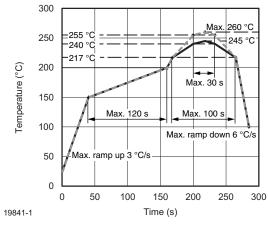


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

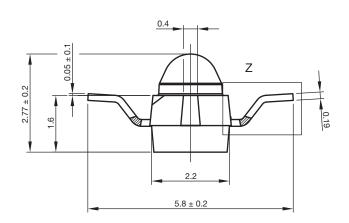
Conditions: T_{amb} < 30 °C, RH < 60 %

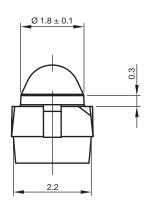
Moisture sensitivity level 2a, according to J-STD-020.

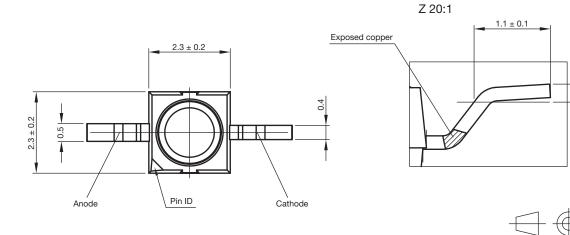
DRYING

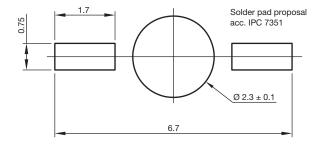
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.

PACKAGE DIMENISONS in millimeters: VSMY2850RGX01







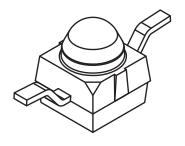


Not indicated tolerances ± 0.1

technical drawings

according to DIN specifications

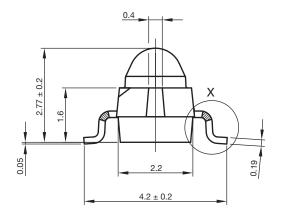
0.254

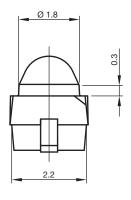


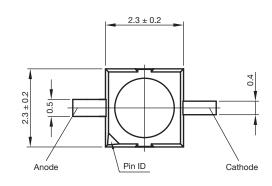
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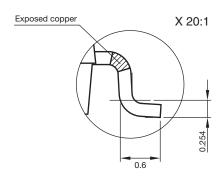
Issue: 1; 18.03.10

PACKAGE DIMENSIONS in millimeters: VSMY2850GX01

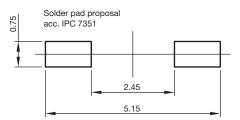




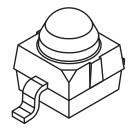








Not indicated tolerances \pm 0.1

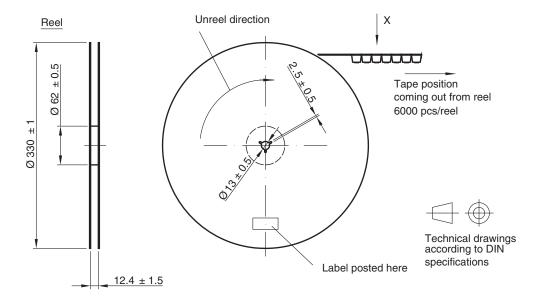


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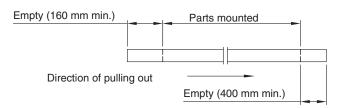
Issue: 1; 18.03.10



TAPING AND REEL DIMENSIONS in millimeters: VSMY2850RGX01

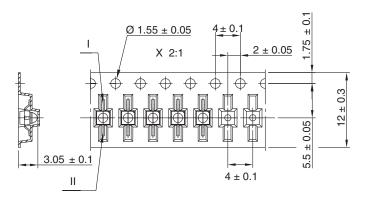


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II
VEMT2000		
VEMT2500	Collector	Emitter
VEMD2000		
VEMD2500	0-4	Al -
VSMB2000	Cathode	Anode
VSMG2000		
VSMY2850RG	Anode	Cathode

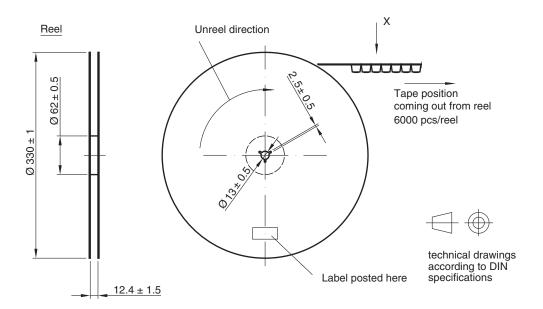


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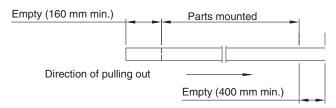
Issue: 2; 18.03.10



TAPING AND REEL DIMENSIONS in millimeters: VSMY2850GX01

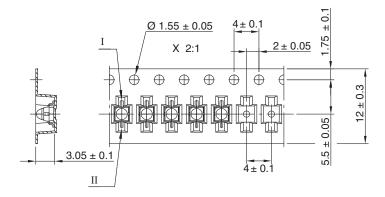


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II
VEMT2020		
VEMT2520	Collector	Emitter
VSMB2020		
VSMG2020	Cathode	Anode
VEMD2020	Calriode	Ariode
VEMD2520		
VSMY2850G	Anode	Cathode



Drawing-No.: 9.800-5091.01-4

Issue: 3; 18.03.10



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